Analog Power AM1433PE

## P-Channel 30-V (D-S) MOSFET

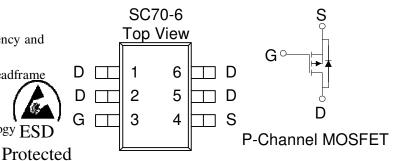
These miniature surface mount MOSFETs utilize a high cell density trench process to provide low  $r_{DS(on)}$  and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

•	Low $r_{DS(on)}$ provides higher efficiency and
	extends battery life

• Low thermal impedance copper leadframe SC70-6 saves board space

Fast switching speed

High performance trench technology ESD



ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25 °C UNLESS OTHERWISE NOTED)						
Parameter	Symbol	Maximum	Units			
Drain-Source Voltage			-30	V		
Gate-Source Voltage			±20	V		
	T <sub>A</sub> =25°C		-4.1			
Continuous Drain Current <sup>a</sup>	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	$\mathbf{I}_{\mathrm{D}}$	-3.3	A		
Pulsed Drain Current <sup>b</sup>		$I_{DM}$	-10			
Continuous Source Current (Diode Conduction) <sup>a</sup>		$I_S$	±1.4	A		
D	$T_A=25^{\circ}C$	D	1.56	W		
Power Dissipation <sup>a</sup>	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	$r_{\rm D}$	0.81	VV		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to 150	°C		

THERMAL RESISTANCE RATINGS							
Parameter	Symbol	Maximum	Units				
N	$t \le 5 \sec$	D	80	OCANI			
Maximum Junction-to-Ambient <sup>a</sup>	Steady-State	$R_{THJA}$	125				

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## Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

SPECIFICATIONS (T <sub>A</sub> = 25°C UNLESS OTHERWISE NOTED)								
Domaria 4 a m	G 1.1	T C. 111	Limits			T 124		
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit		
Static								
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250 \text{ uA}$	-1			V		
Gate-Body Leakage	Igss	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±10	μA		
Zara Cata Valtaga Prain Current	I <sub>DSS</sub>	$V_{DS} = -24 \text{ V}, V_{GS} = 0 \text{ V}$			-1	μА		
Zero Gate Voltage Drain Current	IDSS	$V_{DS} = -24 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 55^{\circ}\text{C}$			-10			
On-State Drain Current <sup>A</sup>	I <sub>D(on)</sub>	$V_{DS} = -5 \text{ V}, V_{GS} = -4.5 \text{ V}$	-5			A		
D i G G D i A		$V_{GS} = -10 \text{ V}, I_D = -1 \text{ A}$			64	— mΩ l		
Drain-Source On-Resistance <sup>A</sup>	r <sub>DS(on)</sub>	$V_{GS} = -4.5 \text{ V}, I_D = -1 \text{ A}$			96			
Forward Tranconductance <sup>A</sup>	g <sub>fs</sub>	$V_{DS} = -5 \text{ V}, I_D = -1 \text{ A}$		9		S		
Diode Forward Voltage	$V_{\mathrm{SD}}$	$I_S = -0.46 \text{ A}, V_{GS} = 0 \text{ V}$		-0.65		V		
Dynamic b								
Total Gate Charge	Qg	V 10 V V 45 V		4				
Gate-Source Charge	Qgs	$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V},$ $I_{D} = -1 \text{ A}$		1		nC		
Gate-Drain Charge	Qgd			2				
Turn-On Delay Time	t <sub>d(on)</sub>			9				
Rise Time	t <sub>r</sub>	$V_{\rm DD} = -10 \text{ V}, I_{\rm L} = -1 \text{ A},$		4		ns		
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GEN}$ = -4.5 V, $R_G$ = 6 $\Omega$		1				
Fall-Time	$t_{\mathrm{f}}$			2				

## Notes

a. Pulse test: PW <= 300us duty cycle <= 2%.

Guaranteed by design, not subject to production testing.

c. Repetitive rating, pulse width limited by junction temperature.

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